

Dynamics of light-induced reflectivity switching in gallium films deposited on silica by pulsed laser ablation: errata

A. V. Rode, M. Samoc, B. Luther-Davies, and E. G. Gamaly

Research School of Physical Sciences and Engineering, Australian National University, Canberra, ACT 0200, Australia

K. F. MacDonald and N. I. Zheludev

Department of Physics and Astronomy, University of Southampton, Southampton SO17 1BJ, UK

In our Letter,¹ the references to silica (e.g., Ga–silica interface, Ga–silica structures, silica substrates) were incorrectly changed to Si. Silica or SiO₂ should have been used throughout the Letter.

Reference

1. A. V. Rode, M. Samoc, B. Luther-Davies, E. G. Gamaly, K. F. MacDonald, and N. I. Zheludev, *Opt. Lett.* **26**, 441 (2001).
OCIS codes: 320.7130, 240.4350, 160.3900, 190.4350, 190.7110.